

W-Band Power Amplifier, 65 to 110 GHz, 15 dB Gain, 13 dBm P_{1dB}

Description:

Model SBP-6531141513-1010-E1 is a GaN based high power amplifier with a typical small signal gain of 15 dB and a nominal P_{1dB} of +13 dBm across the frequency range of 65 to 110 GHz. The DC power requirement for the amplifier is +10 V_{DC}/480 mA. The mechanical configuration offers an in line structure with WR-10 waveguides and UG-387/U-M anti-cocking flanges. Other port configurations, such as with 1 mm connectors or a



right angle structure with WR-10 waveguides, are also available under different model numbers.

Features:

- **High Output Power**
- High Power Added Efficiency (PAE)

Applications:

- **Test Instrumentation**
- **Communication Systems**
- Radar Systems

Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	65 GHz		110 GHz
Gain		15 dB	
P _{1dB}		+13 dBm	
P _{sat}		+18 dBm	
P _{in}			+20 dBm
Input Return Loss		10 dB	
Output Return Loss		10 dB	
DC Voltage	+9 V _{DC}	+10 V _{DC}	+15 V _{DC}
DC Supply Current		480 mA	
Specification Temperature		+25 °C	
Operating Temperature	0 °C		+50 °C

Mechanical Specifications:

Item	Specification	
Input Port	WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange	
Output Port	WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange	
Bias	Solder Pin	
Case Material	Aluminum	
Finish	Gold Plated	
Weight	1.6 Oz	
Size	1.10" (W) X 1.50" (L) X 0.75" (H)	
Outline	BG-SW-2-A	



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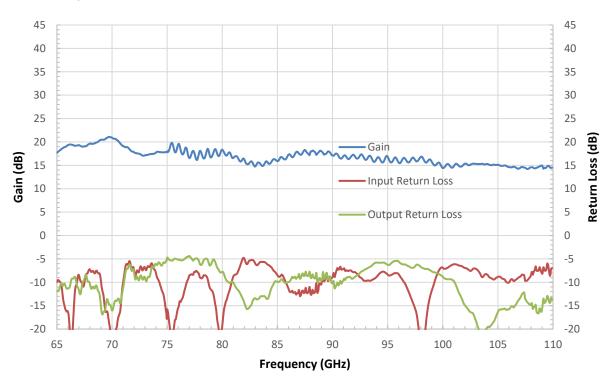


SAGE Millimeter, Inc.

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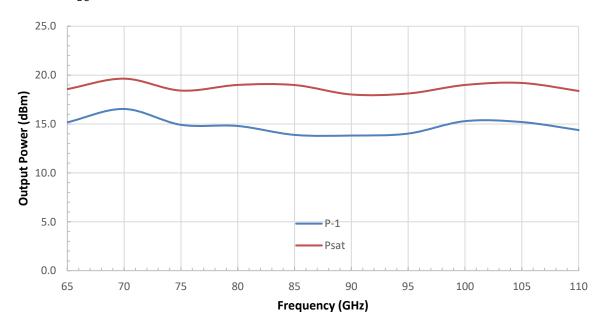
Typical Gain and Return Loss vs. Frequency

Bias: $+10 V_{DC}/472 \text{ mA}$



Output Power vs. Frequency

Bias: $+10 \, V_{DC}/472 \, \text{mA}$





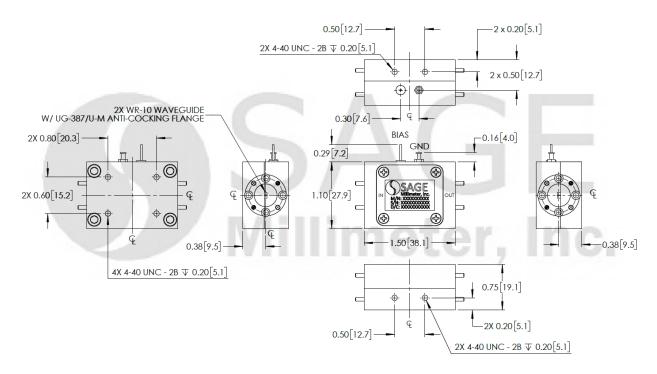
ESD

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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit, slightly.
- All testing was performed under +25 °C case temperature.
- Other mechanical configurations are available under different model numbers.
- Eravant reserves the right to change the information presented without notice.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Any foreign objects in the waveguide will cause performance degradation and may damage the device.



ESD ESD